

10/594391

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

IAP5 Rec'd PCT/PTO 27 SEP 2006

MOSELUND ET AL

Atty. Ref.: 2590-169

Serial No. **Unknown**

Group:

National Phase of: **PCT/IB2005/051049**

International Filing Date: **29 March 2005**

Filed: **Herewith**

Examiner:

For: **LIGHT PHASE MODULATOR**

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September 27, 2006

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

As suggested by 37 C.F.R. 1.97, the undersigned attorney brings to the attention of the Patent and Trademark Office the references listed on the attached form PTO/SB/08a. Copies of the non-U.S. references are enclosed. This is not to be construed as a representation that a search has been made or that no better prior art exists, or that a reference is relevant merely because cited. A copy of the International Search Report, as well as the Written Opinion, are also enclosed.

The Examiner is requested to initial the attached form PTO/SB/08a and to return a copy of the initialed document to the undersigned as an indication that the attached references have been considered and made of record.

Respectfully submitted,

NIXON & VANDERHYE P.C.

By:



Duane M. Byers
Reg. No. 33,363

DMB:Imy
901 North Glebe Road, 11th Floor
Arlington, VA 22203-1808
Telephone: (703) 816-4000
Facsimile: (703) 816-4100

INFORMATION DISCLOSURE CITATION

ATTY. DOCKET NO.

SERIAL NO.

2590-169

Unknown

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APPLICANT

MOSELUND ET AL

IAP5 Rec'd PCT/PTO 27 SEP 2005

(Use several sheets if necessary)

FILING DATE

GROUP

Herewith

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	6,298,177	10/2001	House			

FOREIGN PATENT DOCUMENTS

DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
WO 03/044590 A1	5/2003	WIPO			

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	International Search Report mailed September 14, 2005 in PCT/IB2005/051049.
	Written Opinion mailed September 14, 2005 in PCT/IB2005/051049.

*Examiner

Date Considered

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.